

## 50-60Hz RECTIFICATION BRIDGE

### MAJOR PRODUCT CHARACTERISTICS

$I_{F(AV)}$	4 A
$V_{RRM}$	600 V / 800 V
$V_F(\text{max})$	1.05 V

### FEATURES AND BENEFITS

- Dielectric strength of 2000V
- High Surge overload rating
- High Surge current capability
- UL94V0
- Planar technology

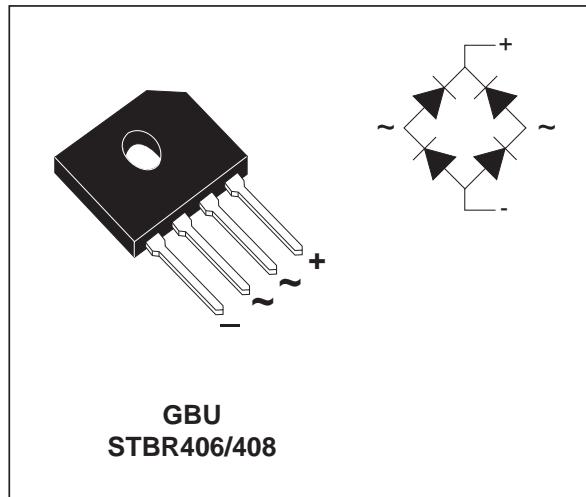
### DESCRIPTION

Single-phase 4A Bridge for 50 & 60Hz rectification in Switch Mode Power Supplies.

Application: Home appliances, Automation, Telecommunications, PC, Servers.

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		STBR406	STBR408	Unit
$V_{RRM}$	Repetitive peak reverse voltage		600	800	V
$V_{RMS}$	RMS Voltage		420	560	V
$V_{DC}$	DC Blocking voltage		600	800	V
$I_{F(AV)}$	Average Forward Current	$T_C = 90^\circ\text{C}$	4		A
$I_{FSM}$	Non repetitive surge peak forward current	tp = 8.3 ms Single sine wave (JEDEC method)	120		A
$I^2t$	Rating for Fusing (tp < 8.3ms)		60		$\text{A}^2\text{s}$
$T_j$	Maximum operating junction temperature		150		$^\circ\text{C}$
$T_{stg}$	Storage temperature range		- 50 to 150		$^\circ\text{C}$



### THERMAL PARAMETERS

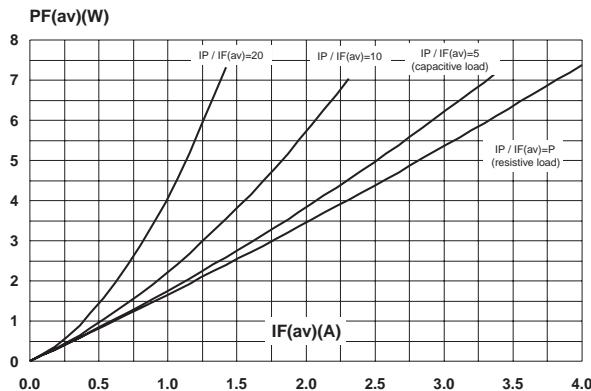
Symbol	Parameter	Min.	Typ.	Max.	Unit
$R_{th(j-c)}$	Junction to case		7.6	8.4	°C/W
$R_{th(j-a)}$	Junction to ambient			35	°C/W

### ELECTRICAL CHARACTERISTICS

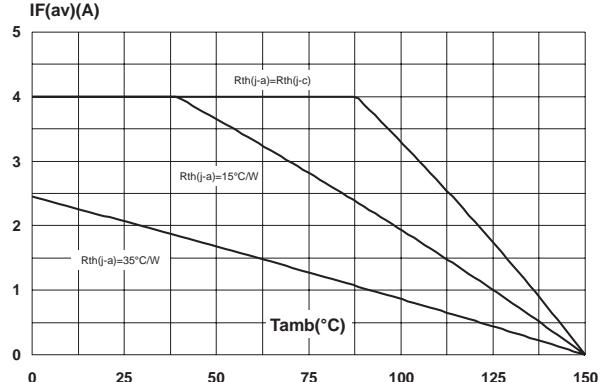
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_F$	Forward voltage drop	$I_F = 4A$			1.05	V
$I_R$	Reverse leakage current per leg	$V_R = V_{RRM}$	$T_j = 25^\circ C$		5	$\mu A$
			$T_j = 125^\circ C$		50	$\mu A$
C	Junction capacitance per leg (note 1)			40		pF

Note 1: Measured at 1MHz and applied reverse voltage of 4V.

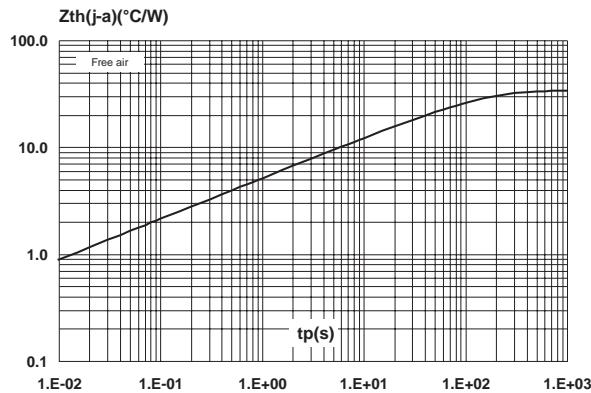
**Fig. 1:** Average power dissipation of bridge versus average output current.



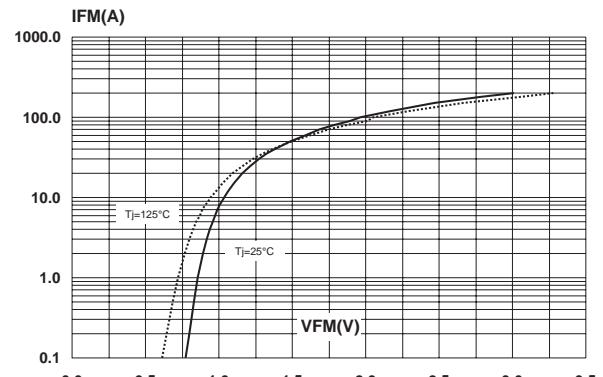
**Fig. 2:** Average output current versus ambient temperature (resistive load or inductive load)



**Fig. 3:** Variation of thermal impedance junction to ambient versus pulse duration (printed circuit board epoxy FR4).

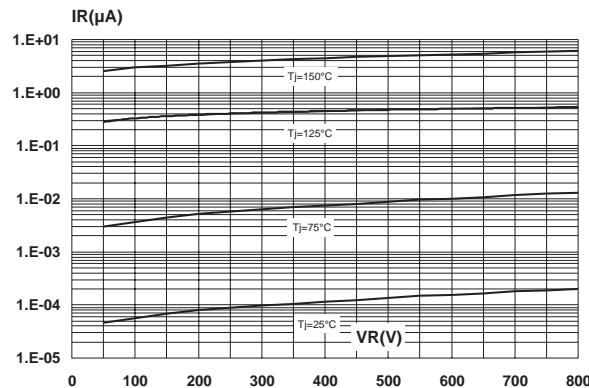


**Fig. 4:** Forward voltage drop versus forward current (typical values, per leg).

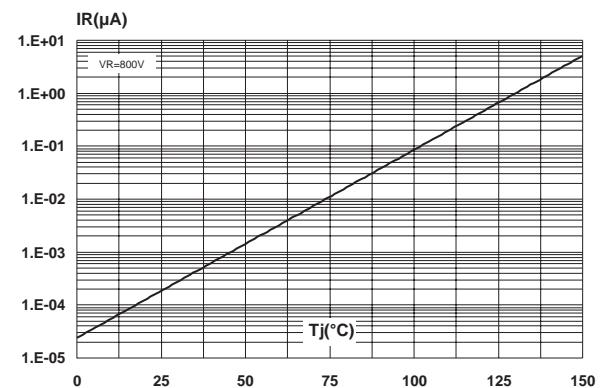


## STBR406/408

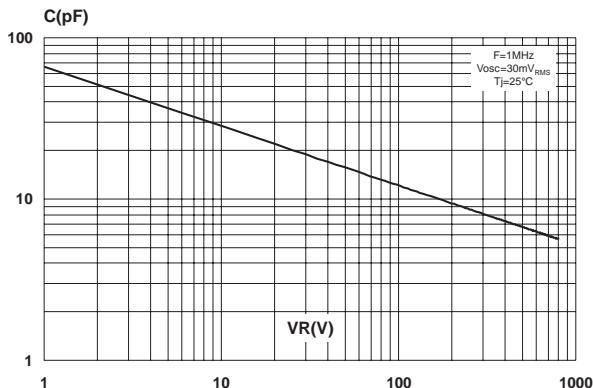
**Fig. 5:** Reverse leakage current versus reverse voltage applied (typical values, per leg).



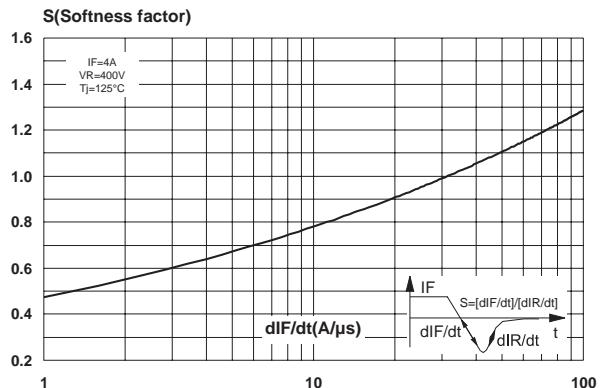
**Fig. 6:** Reverse leakage current versus junction temperature (typical values).



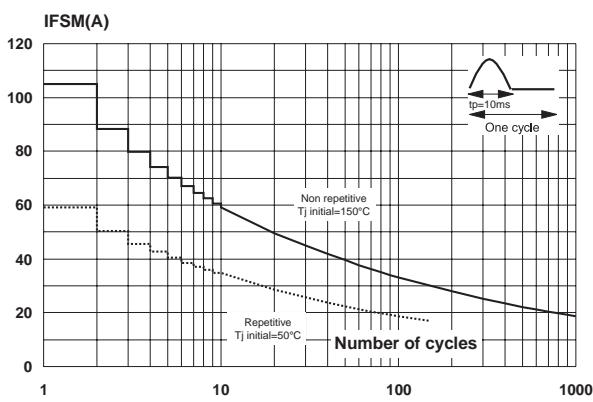
**Fig. 7:** Junction capacitance versus reverse voltage applied (typical values).



**Fig. 8:** Softness factor versus dIF/dt (typical values).

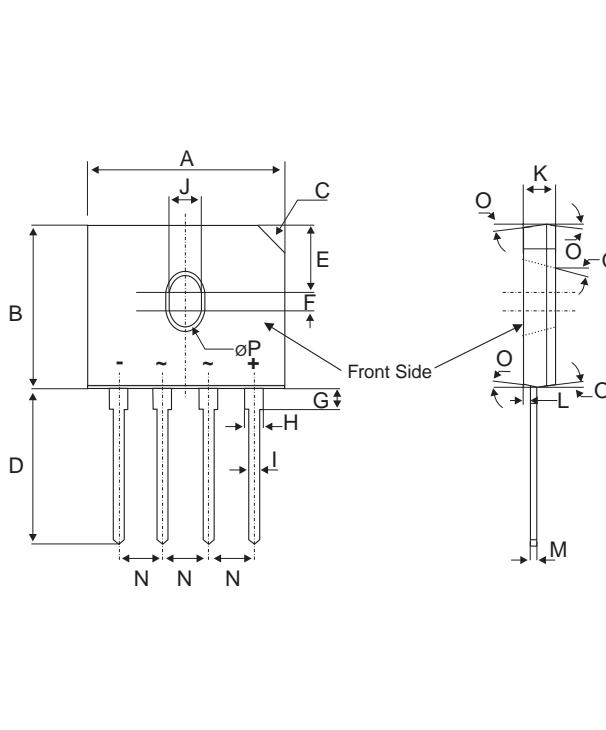


**Fig. 9:** Surge peak forward current versus number of cycles (per leg).



## PACKAGE MECHANICAL DATA

### GBU



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	21.8	22.3	0.86	0.88
B	18.3	18.8	0.72	0.74
C	3.2 typ.	45°	0.125 typ.	45°
D	17.5	18	0.69	0.71
E	7.4	7.9	0.29	0.31
F	1.65	2.16	0.065	0.085
G	2.25	2.75	0.089	0.108
H	1.95	2.35	0.077	0.093
I	1.02	1.27	0.04	0.05
J	3.5	4.1	0.14	0.16
K	3.3	3.56	0.13	0.14
L	0.76	1	0.03	0.04
M	0.46	0.56	0.018	0.022
N	4.83	5.33	0.19	0.21
O	7° typ.		7° typ.	
P	1.9 typ.		0.075 typ.	
Q	7° typ.		7° typ.	

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STBR406	STBR406	GBU	4.0g	20	Tube
STBR408	STBR408	GBU	4.0g	20	Tube

- Epoxy meets UL94,V0
- Cooling method: C
- Recommended torque value: 0.8 m.N
- Maximum torque value: 1.0 m.N

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